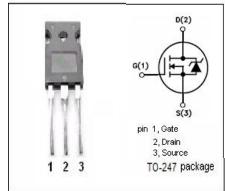


isc N-Channel MOSFET Transistor

FDL100N50F

• FEATURES

- · With TO-247 packaging
- With low gate drive requirements
- · Easy to drive
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

· Switching applications



• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	500	V
V _{GSS}	Gate-Source Voltage	±30	V
ID	Drain Current-Continuous@Tc=25℃ Tc=100℃	100 60	А
I _{DM}	Drain Current-Single Pulsed	400	А
P _D	Total Dissipation	2500	W
Tj	Operating Junction Temperature	-50~150	${\mathbb C}$
T _{stg}	Storage Temperature	-50~150	${\mathbb C}$

	mm	
DIM	MIN	MAX
Α	19.80	20.20
В	15.40	15.80
С	4.90	5.10
D	0.90	1.10
E	1.40	1.60
F	1.90	2.10
G	10.80	11.00
Н	2.40	2.60
J	0.50	0.70
K	19.50	20.50
P	3.90	4.10
Q	3.30	3.50
U	5.20	5.40
V	2.90	3.10

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.05	°C/W

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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	500			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =50A		43	55	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 500V; V _{GS} = 0V;@Tc=25°C V _{DS} = 400V; V _{GS} = 0V;Tc=125°C			10 100	μА
V _{SDF}	Diode forward voltage	I _{SD} =100A, V _{GS} = 0 V			1.5	V



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